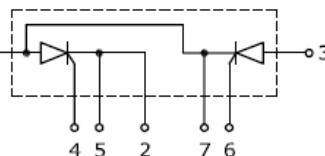




PRELIMINARY DATASHEET

Phase Control Thyristor, Half-Bridge Configuration In iQPak™ Power Module Package

- High voltage & high current
- Low on-state voltage
- Suitable for over voltage control, motor control circuit and heating control system
- Pb-free lead finish; RoHS compliant



MAXIMUM RATINGS (per leg), $T_C = 25^\circ\text{C}$ unless otherwise noted

Parameter	Symbol	Value	Units
Average on-state current $T_J = 125^\circ\text{C}$	$I_{T(\text{AV})}$	45	A
Continuous RMS on-state current as AC switch	$I_{T(\text{RMS})}$	70	
Non-repetitive surge peak on-state current $T_J = 125^\circ\text{C}, t_p = 10 \text{ ms, applied rated } V_{\text{RRM}}$	I_{SM}	630	
$ I t$ value for fusing $T_J = 125^\circ\text{C}, t_p = 10 \text{ ms, applied rated } V_{\text{RRM}}$	$I_{\sharp t}$	1980	A·s
Peak gate current $T_J = 125^\circ\text{C}$	I_{GM}	2.5	A
Maximum repetitive peak off-state voltage $I_R = 100\mu\text{A}$	V_{DRM}	1600	V
Maximum repetitive reverse voltage $I_R = 100\mu\text{A}$	V_{RRM}	1600	
Maximum reverse leakage current	I_{RRM}	0.2	mA
Maximum direct leakage current	I_{DRM}	0.2	
Operating junction and storage temperature	T_J, T_{stg}	-40... +125	°C

Thermal Resistance (per leg)

Parameter	Symbol	Max. Value	Units
Characteristics			
Thermal resistance, junction to case	R_{thJC}	1.0	°C /W
Thermal resistance, junction to ambient	R_{thJA}	40	
Isolation voltage, RMS (measured between terminals and mounting base, 50-60 Hz, for 1 minute)	V_{iso}	2500	V

Electrical Characteristics (per leg), at $T_J = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
Maximum required DC gate current to trigger	I_{GT}	$\text{Anode Supply} = 6\text{V}, R_L = 33\Omega$	-	-	100	mA
Maximum required DC gate voltage to trigger	V_{GT}		-	-	1.5	
Maximum holding current	I_H	$T_J = 25^\circ\text{C}$, anode supply 6 V, resistive load	-	-	150	V
Maximum latching current	I_L		-	-	300	
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_{J\text{max}}$ linear to 67% V_{DRM}	-	-	1000	V/μs
Maximum peak on-state voltage	V_{TM}	141 A	-	-	1.65	V
Maximum peak gate power	P_{GM}		-	10	-	W

CAUTION: These devices are ESD sensitive. Use proper handling procedure.

Package Outline Drawing

